HD74LS241

●Octal Buffers/Line Drivers/Line Receivers (non inverted three-state outputs)

■BLOCK DIAGRAM (½)

IFUNCTION TABLE

	Inputs		Output
1 <u>G</u>	2G	A	Y
Н	L	×	Z
L	Н	Н	H
L	Н	L.	L

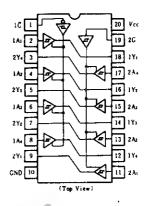
Note) H; high level,

L; low level,

X; irrelevant

Z; off (high-impedance) state of a 3-state output

PIN ARRANGEMENT



ELECTRICAL CHARACTERISTICS ($Ta = -20 \sim +75^{\circ}$ C)

	Item	Symbol	Test Condition	S	min 🤞	typ"	max	Unit
Input voltage		VIH			2.0	Y	U -	V
		VIL		20	火工	A-U	0.8	v
Hysteresis		$V_T^+ - V_T^-$	Vcc=4.75V	4 3	0.2	0.4		V
Output voltage		Voн	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.8 \text{V},$	Ion = -3mA	2.4	_	v	
			$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V}, V_{IL} = 0.5 \text{V}, I_{OH} = -15 \text{mA}$		2.0	-	-	
			$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V},$	IoL = 12mA	_	- 0.4	v	
		Vol	$V_{IL}=0.8V$	IoL = 24mA	-	-	0.5	.
Output current		Іогн	$V_{CC}=5.25V$, $V_{IH}=2V$,	Vo=2.7V			20	μΑ
		Iozi.	$V_{IL} = 0.8V$	Vo=0.4V	_		- 20	
Input current		In	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$		_		20	μA
		In	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$		_	-	-0.2	mA
		Iı .	$V_{CC} = 5.25 \text{V}, V_{I} = 7 \text{V}$		_	_	0.1	m,A
Short-circui	t output current	los	V _{CC} =5.25V		-40	_	225	mA
Outputs high				_	13	23		
Supply Out	Outputs low	Icc	Vcc = 5.25V		_	27	46	mA
	All outputs disabled				-	32	54	
Input clamp voltage V_{IK} $V_{CC}=4.75V$,		$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$				-1.5	V	

^{*} VCC=5V, Ta=25°C

ESWITCHING CHARACTERISTICS ($V_{CC} = 5V$, $T_a = 25^{\circ}C$)

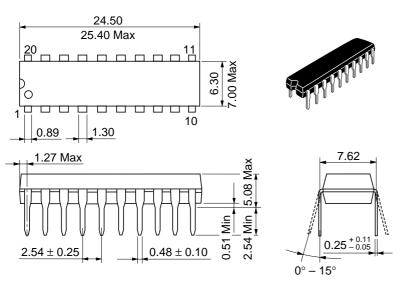
Item	Symbol	Test Conditions	min	typ	max	Unit
Propagation delay time	tPLH	$C_L = 45 \mathrm{pF}, R_L = 667 \Omega$	-	12	18	ns
	tphL		_	12	18	
Output enable time	!ZL		_	20	30	ns
	tzn		_	15	23	ns
Output disable time	tLZ	$C_L = 5 \text{pF}, R_L = 667 \Omega$		15	25	ns
	tHZ			10	18	ns

Note) Refer to Test Circuit and Waveform of the Common Item

^{**} ICC is measured with all outputs open.



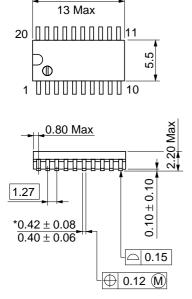
Unit: mm



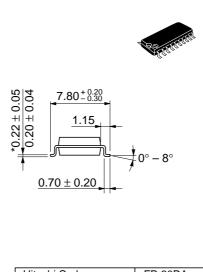
Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g







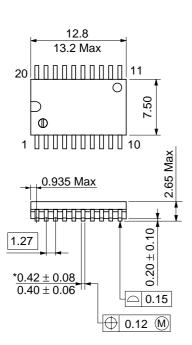
12.6



Hitachi Code	FP-20DA
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.31 g

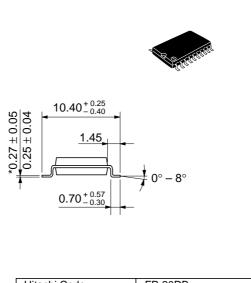
*Dimension including the plating thickness
Base material dimension





*Dimension including the plating thickness

Base material dimension



Unit: mm

Hitachi Code FP-20DB

JEDEC Conforms

EIAJ —

Weight (reference value) 0.52 g

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Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 URI

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group.

Whitebrook Park

Lower Cookham Road

Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd

Taipei Branch Office 3F, Hung Kuo Building. No.167 Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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